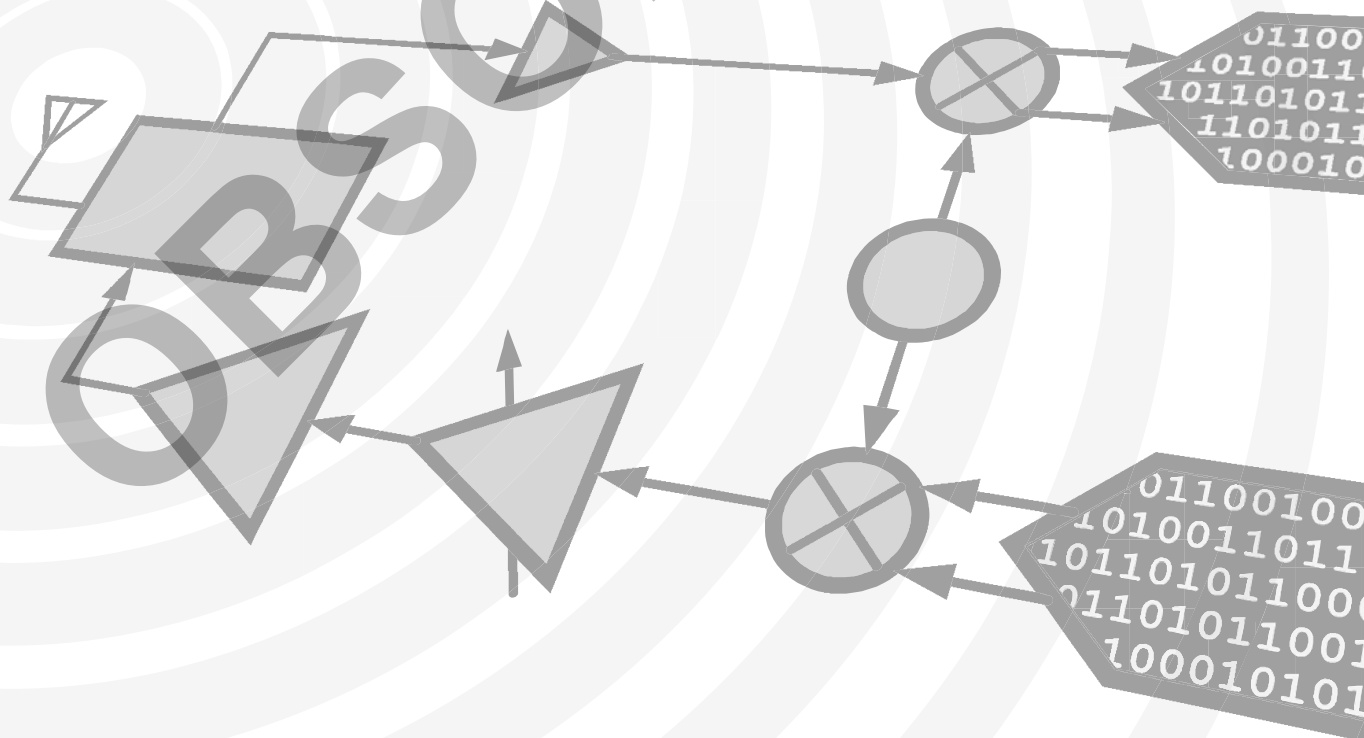




Hittite
MICROWAVE PRODUCTS
FROM ANALOG DEVICES

Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



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OBSOLETE

Typical Applications

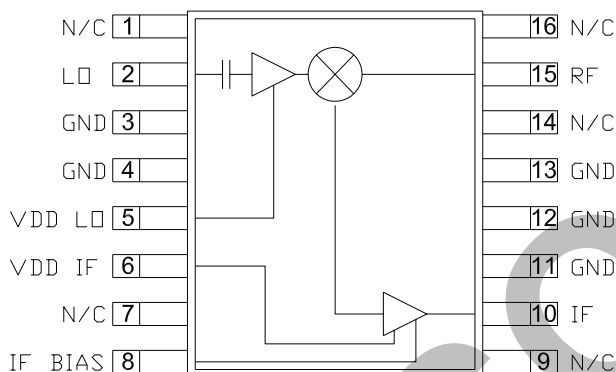
The HMC421QS16 / HMC421QS16E is ideal for:

- GSM, GPRS & EDGE Infrastructure
- CDMA, WCDMA Infrastructure
- PHS & PDC Infrastructure

Features

- Input IP3: +19 dBm
- Integrated IF & LO Amps: +10 dBm LO
- Conversion Gain: 9 dB
- Noise Figure: 9 dB
- Single Positive Supply: +5V @ 60 mA

Functional Diagram



General Description

The HMC421QS16 & HMC421QS16E are high linearity down-converter receiver ICs suitable for PCS/UMTS infrastructure applications. The receiver IC is designed to support UMTS applications where a high third order intercept point (OIP3) is required. A passive mixer coupled with a high dynamic range IF amplifier achieves an Input IP3 of +19 dBm. The converter provides a gain of 8 dB and 9 dB typical single side band noise. The IC operates from positive +5V rails and consumes 60 mA of current. The design requires no external Baluns. The mixer supports IF frequencies between 50 MHz and 300 MHz.

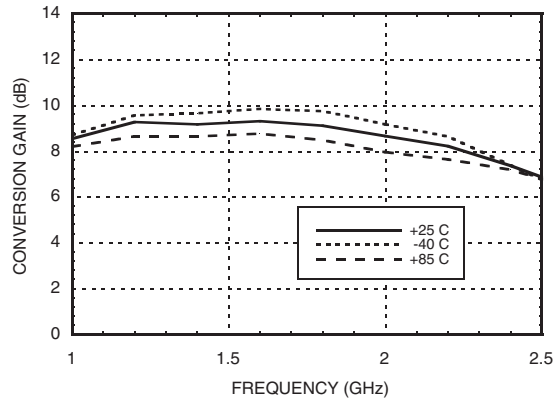
Electrical Specifications, $T_A = +25^\circ\text{C}$, LO = +10 dBm, Vdd = 5V

Parameter	IF= 100 MHz			IF= 250 MHz			IF= 250 MHz			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF	1.4 - 1.6			1.7 - 2.0			2.0 - 2.3			GHz
Frequency Range, LO	1.3 - 1.55			1.4 - 1.95			1.7 - 2.25			GHz
Frequency Range, IF*	50 - 100			50 - 300			50 - 300			MHz
Conversion Gain	6	9		7	9		5	8		dB
Noise Figure (SSB)		11			9			9.5		dB
LO to RF Isolation	23	29		28	33		26	32		dB
LO to IF Isolation	35	42		42	52		50	60		dB
RF to IF Isolation	35	42		42	52		50	60		dB
IP3 (Input)	15	18		17	19		17	20		dBm
1 dB Compression (Input)	3	6		4	6.5		4	7		dBm
LO Input Drive Level (Typical)	+8 to +12			+8 to +12			+8 to +12			dBm
Supply Current (Idd for LO & IF) (IF bias resistor= 6.8 Ohms)		84	105		84	105		84	105	mA

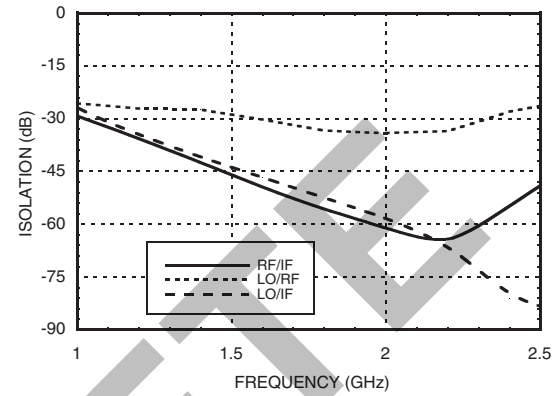
* If matching must be tuned for optimal results, see application circuit herein.

Conversion Gain

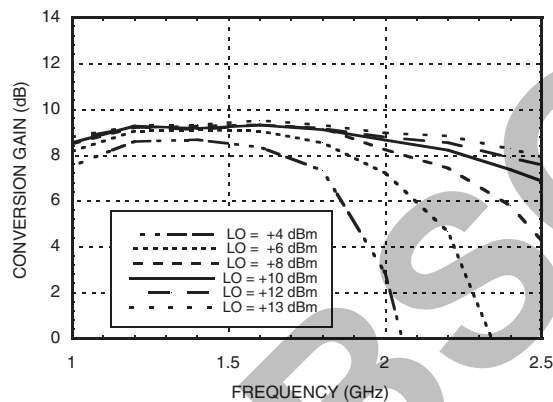
vs. Temperature @ LO = +10 dBm



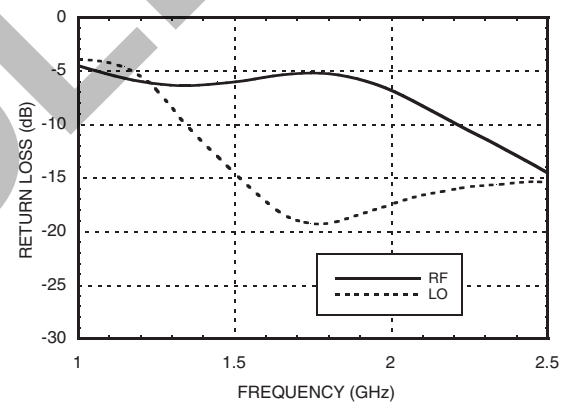
Isolation @ LO = +10 dBm



Conversion Gain vs. LO Drive

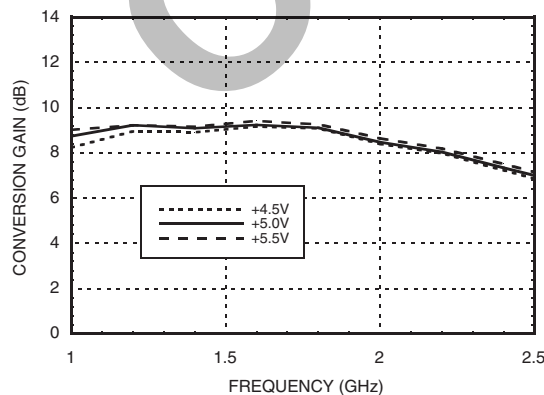


Return Loss @ LO = +10 dBm

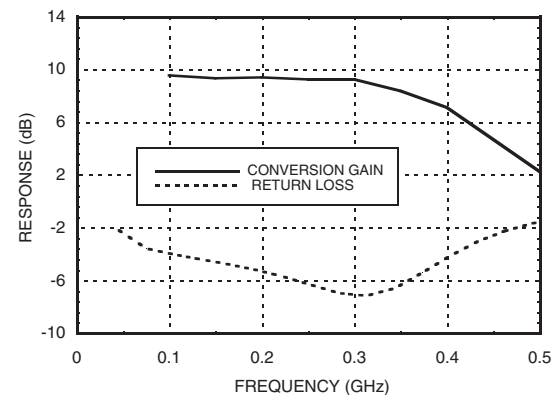


Conversion Gain

vs. Vdd @ LO = +10 dBm



IF Bandwidth @ LO = +10 dBm





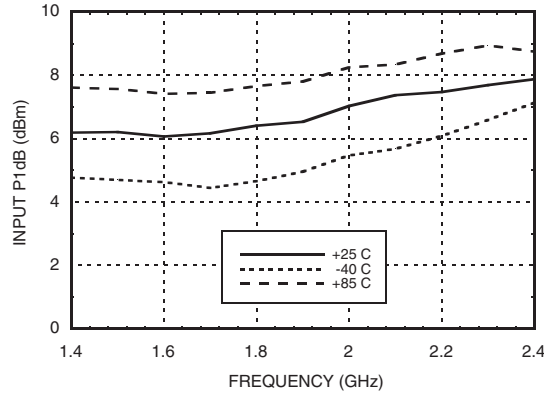
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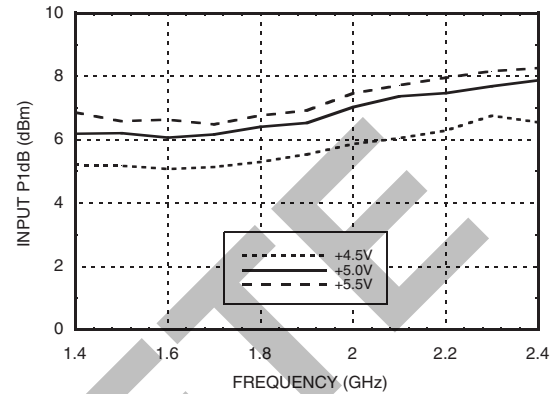
HMC421QS16 / 421QS16E

PCS/UMTS HIGH IP3 RFIC DOWNCONVERTER, 1.4 - 2.3 GHz

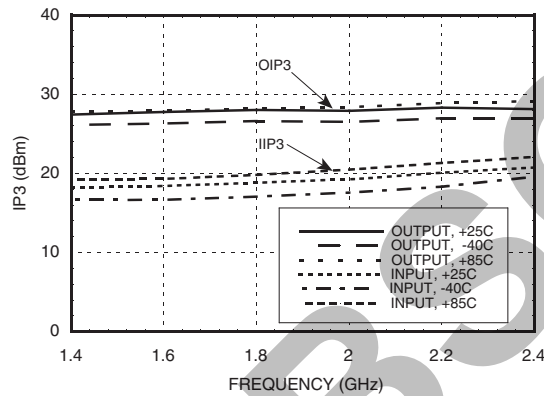
**Input P1dB vs.
Temperature @ LO = +10 dBm**



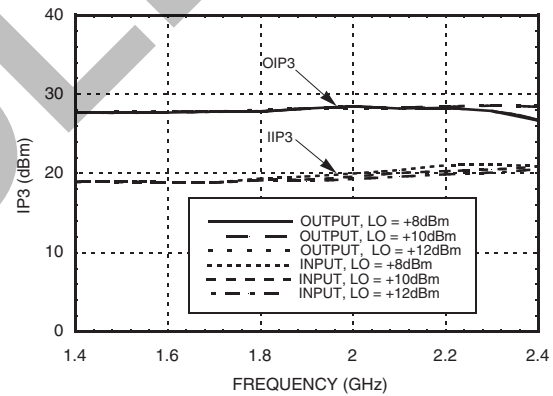
Input P1dB vs. Vdd @ LO = +10 dBm



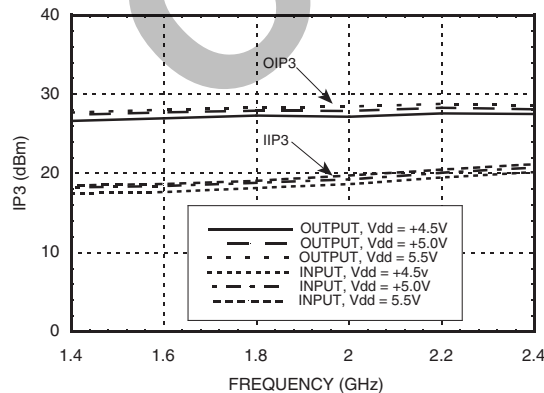
**Input and Output IP3 vs.
Temperature @ LO = +10 dBm***



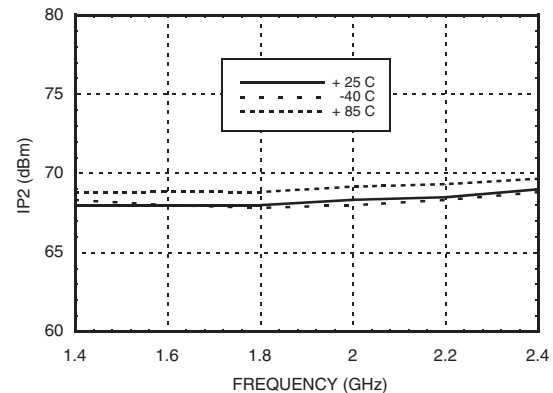
Input and Output IP3 vs. LO Drive*



**Input and Output IP3
vs. Vdd @ LO = +10 dBm***



**Input IP2 vs.
Temperature @ LO = +10 dBm***



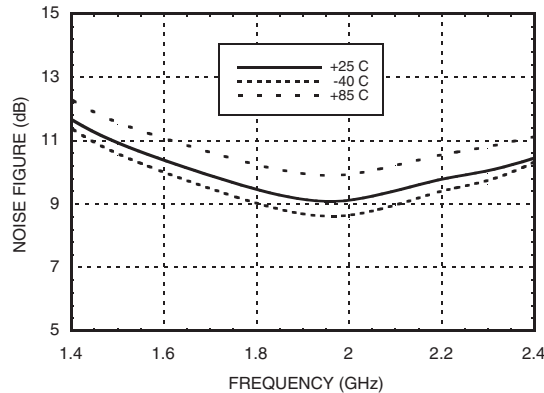
* Two-tone input power = -5 dBm each tone, 1 MHz spacing.

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

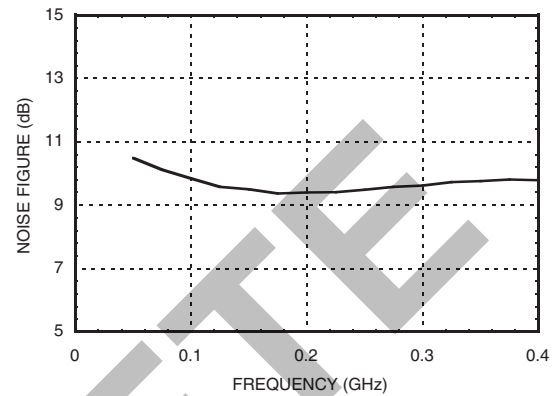
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

**Noise Figure vs. Temperature,
Swept LO, Fixed IF = 250 MHz**



**Noise Figure
Swept IF, Fixed LO = 2 GHz**



MxN Spurious @ IF Port

mRF	nLO				
	0	1	2	3	4
0	XX	42	55	47	52
1	65	0	66	80	89
2	>108	103	50	99	106
3	>108	>108	>108	80	>108
4	>108	>108	>108	>108	>108

RF = 2.05 GHz @ -10 dBm
LO = 1.8 GHz @ +10 dBm
All values in dBc relative to the IF power level.

Harmonics of LO

LO Freq. (GHz)	nLO Spur @ RF Port			
	1	2	3	4
1.4	27	16	33	33
1.6	30	19	33	42
1.8	32	19	29	35
2.0	33	19	30	49
2.2	33	20	34	45
2.4	28	20	34	42

LO = +10 dBm
All values in dBc below input LO level @ RF port.



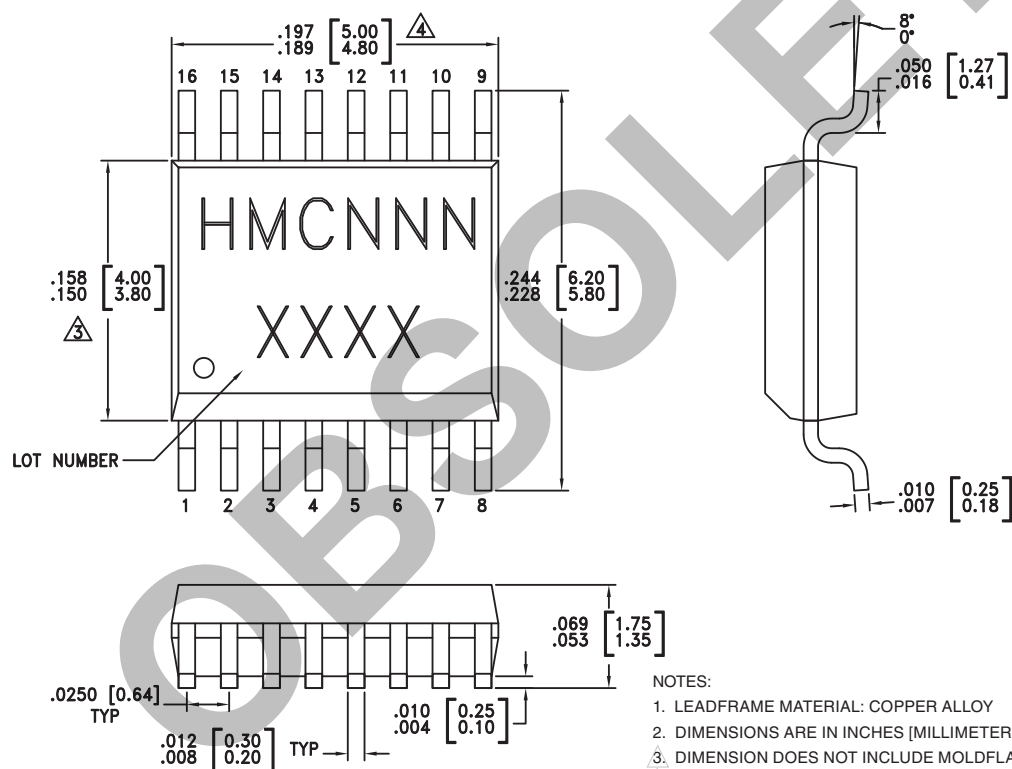
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**HMC421QS16 / 421QS16E****PCS/UMTS HIGH IP3 RFIC
DOWNCONVERTER, 1.4 - 2.3 GHz****Absolute Maximum Ratings**

RF / IF Input (Vdd = +5V)	+13 dBm
LO Drive (Vdd = +5V)	+15 dBm
Vdd (LO or IF)	+7 Vdc
Channel Temperature	150°C
Continuous P _{diss} (T = 85°C) (Derate 6.34 mW/°C above 85°C)	0.41 W
Storage Temperature	-65 to +150°C
Operating Temperature	-40 to +85°C

Typical Supply Current vs. Vdd

Vdd (LO + IF) (Vdc)	(I _{dd}) mA
4.5	61
5.0	62
5.5	63

**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS****Outline Drawing****NOTES:**

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC421QS16	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	HMC421 XXXX
HMC421QS16E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	HMC421 XXXX

[1] Max peak reflow temperature of 235 °C

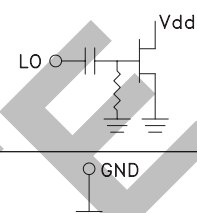
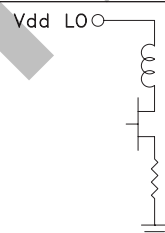
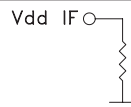
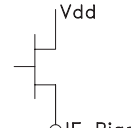
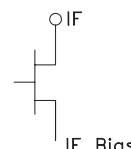
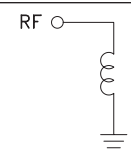
[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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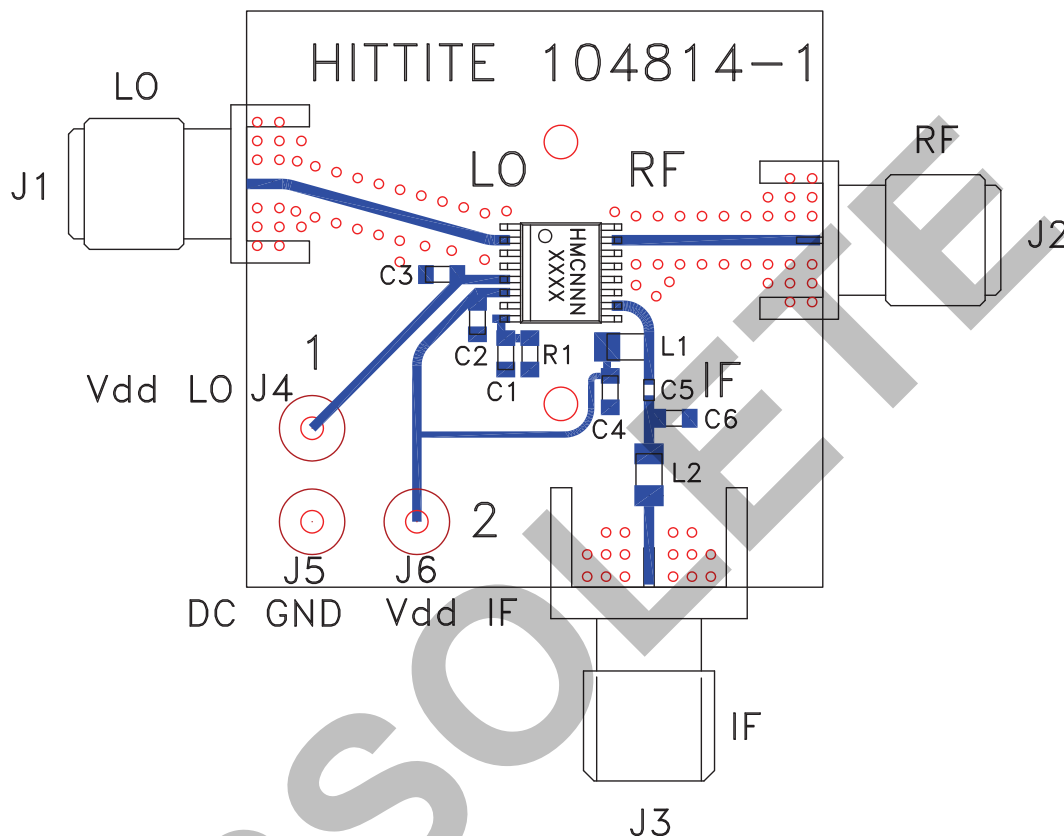
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 7, 9, 14, 16	N/C	Not Connected	
2	LO	This pin is AC coupled and matched to 50 Ohm from 1.3 - 2.5 GHz.	
3, 4, 11, 12, 13	GND	Pin must connect to RF ground.	
5	Vdd LO	Power supply for the LO amplifier. One external RF bypass capacitor (10,000 pF) is required.	
6	Vdd IF	Bias voltage for IF amplifier. One external RF bypass capacitor (10,000 pF) is required.	
8	IF Bias	DC bias setting for IF amplifier.	
10	IF	Output of IF and bias port for amplifier. A pull up inductor (L1), output matching network (C5, C6, L2), and 10,000 pF bypass capacitor (C4) are required.	
15	RF	This pin is DC coupled and matched to 50 Ohm from 1.7 - 2.5 GHz.	



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**HMC421QS16 / 421QS16E****PCS/UMTS HIGH IP3 RFIC
DOWNCONVERTER, 1.4 - 2.3 GHz****Evaluation PCB****List of Materials for Evaluation PCB 105087 ^[1]**

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J6	DC Pins
C1	1000 pF Chip Capacitor, 0603 Pkg.
C2, C3, C4	0.01 μ F Chip Capacitor, 0603 Pkg.
C5	82 pF Chip Capacitor, 0402 Pkg.
C6	6 pF Chip Capacitor, 0603 Pkg.
L1	150 nH Chip Inductor, 0805 Pkg.
L2	27 nH Chip Inductor, 0805
R1	6.8 Ohm Resistor, 0603
U1	HMC421QS16 / HMC421QS16E Mixer
PCB ^[2]	104814 Evaluation Board, 1.100" x 1.100"

[1] Reference this number when ordering complete evaluation PCB

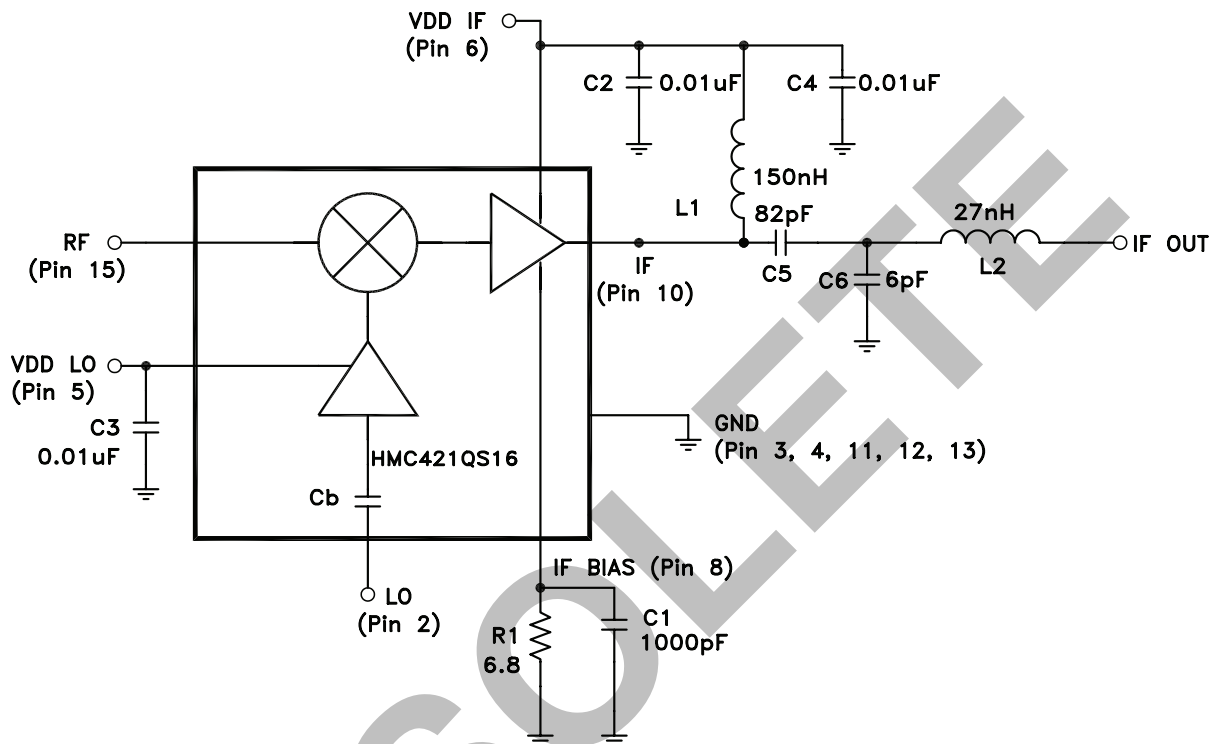
[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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Application Circuit



Notes:

1. Pin 5 and Pin 6 may be connected to a common Vdd supply.
2. Select C6 & L2 to optimize IF frequency. Values for IF = 250 MHz are shown.